

## 600V / 300A 2 in one-package

### ■ Features

- VCE(sat) classified for easy parallel connection
- High speed switching
- Voltage drive
- Low inductance module structure

### ■ Applications

- Inverter for Motor drive
- AC and DC Servo drive amplifier
- Uninterruptible power supply
- Industrial machines, such as Welding machines

### ■ Maximum ratings and characteristics

#### ● Absolute maximum ratings (at Tc=25°C unless otherwise specified)

Item	Symbol	Rating	Unit
Collector-Emitter voltage	V <sub>CEs</sub>	600	V
Gate-Emitter voltage	V <sub>GEs</sub>	±20	V
Collector current	Continuous	I <sub>c</sub>	300
	1ms	I <sub>c</sub> pulse	600
		-I <sub>c</sub>	300
	1ms	-I <sub>c</sub> pulse	600
Max. power dissipation	P <sub>c</sub>	1100	W
Operating temperature	T <sub>j</sub>	+150	°C
Storage temperature	T <sub>stg</sub>	-40 to +125	°C
Isolation voltage	V <sub>is</sub>	AC 2500 (1min.)	V
Screw torque	Mounting *1	3.5	N·m
	Terminals *2	4.5	N·m

\*1: Recommendable value : 2.5 to 3.5 N·m (M5) or (M6)

\*2: Recommendable value : 3.5 to 4.5 N·m (M6)

#### ● Electrical characteristics (at T<sub>j</sub>=25°C unless otherwise specified)

Item	Symbol	Characteristics			Conditions	Unit
		Min.	Typ.	Max.		
Zero gate voltage collector current	I <sub>CEs</sub>	—	—	2.0	V <sub>GE</sub> =0V, V <sub>CE</sub> =600V	mA
Gate-Emitter leakage current	I <sub>GEs</sub>	—	—	30	V <sub>CE</sub> =0V, V <sub>GE</sub> =±20V	μA
Gate-Emitter threshold voltage	V <sub>GE(th)</sub>	4.5	—	7.5	V <sub>CE</sub> =20V, I <sub>c</sub> =300mA	V
Collector-Emitter saturation voltage	V <sub>CE(sat)</sub>	—	—	2.8	V <sub>GE</sub> =15V, I <sub>c</sub> =300A	V
Input capacitance	C <sub>ies</sub>	—	19800	—	V <sub>GE</sub> =0V	pF
Output capacitance	C <sub>oes</sub>	—	4400	—	V <sub>CE</sub> =10V	
Reverse transfer capacitance	C <sub>res</sub>	—	2000	—	f=1MHz	
Turn-on time	t <sub>on</sub>	—	0.6	1.2	V <sub>CC</sub> =300V	μs
		—	0.2	0.6	I <sub>c</sub> =300A	
Turn-off time	t <sub>off</sub>	—	0.6	1.0	V <sub>GE</sub> =±15V	μs
		—	0.2	0.35	R <sub>G</sub> =6.8ohm	
Diode forward on voltage	V <sub>F</sub>	—	—	3.0	I <sub>F</sub> =300A, V <sub>GE</sub> =0V	V
Reverse recovery time	t <sub>rr</sub>	—	—	0.3	I <sub>F</sub> =300A	μs

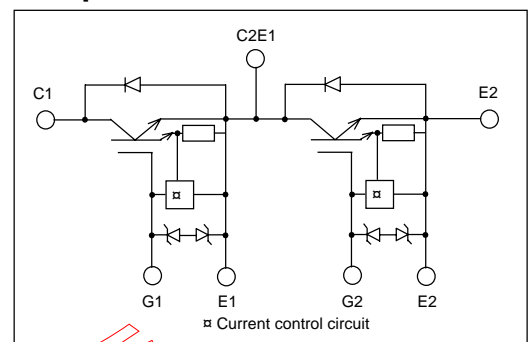
#### ● Thermal resistance characteristics

Item	Symbol	Characteristics			Conditions	Unit
		Min.	Typ.	Max.		
Thermal resistance	R <sub>th(j-c)</sub>	—	—	0.11	IGBT	°C/W
	R <sub>th(j-c)</sub>	—	—	0.15	Diode	°C/W
	R <sub>th(c-f)*</sub>	—	0.025	—	the base to cooling fin	°C/W

\*: This is the value which is defined mounting on the additional cooling fin with thermal compound



### ■ Equivalent Circuit Schematic

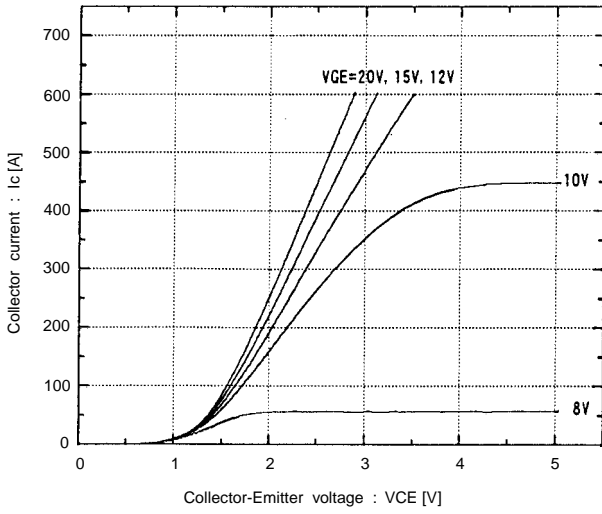


#### ● VCE(sat) classification

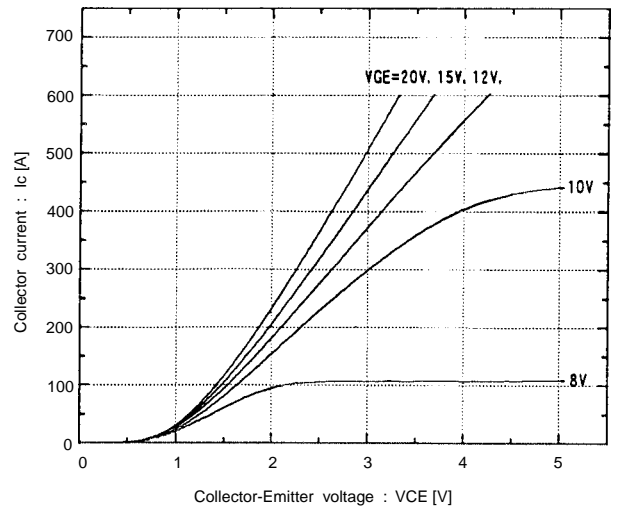
Rank	Length	Conditions
F	1.85 to 2.10V	I <sub>c</sub> = 300A V <sub>GE</sub> = 15V T <sub>j</sub> = 25°C
A	2.00 to 2.25V	
B	2.15 to 2.40V	
C	2.30 to 2.60V	
D	2.50 to 2.80V	

Characteristics (Representative)

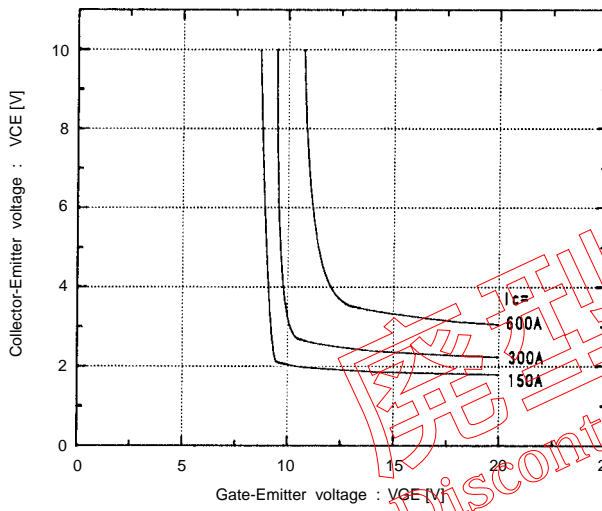
Collector current vs. Collector-Emitter voltage  
Tj=25°C



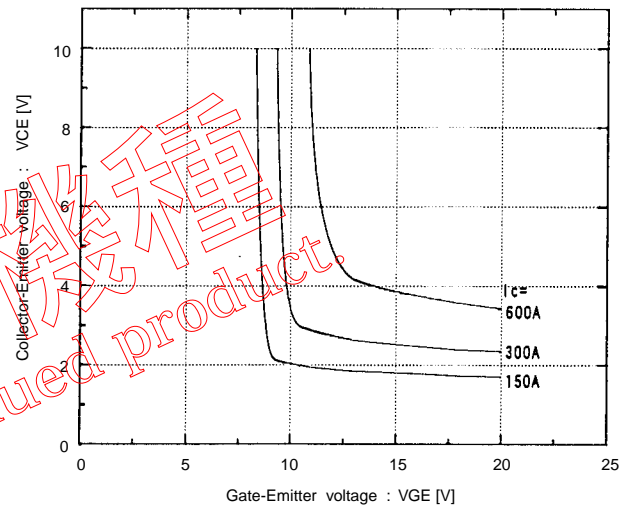
Collector current vs. Collector-Emitter voltage  
Tj=125°C



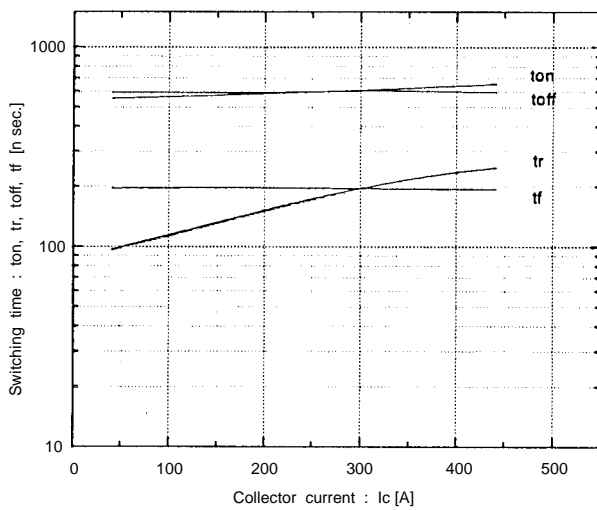
Collector-Emitter vs. Gate-Emitter voltage  
Tj=25°C



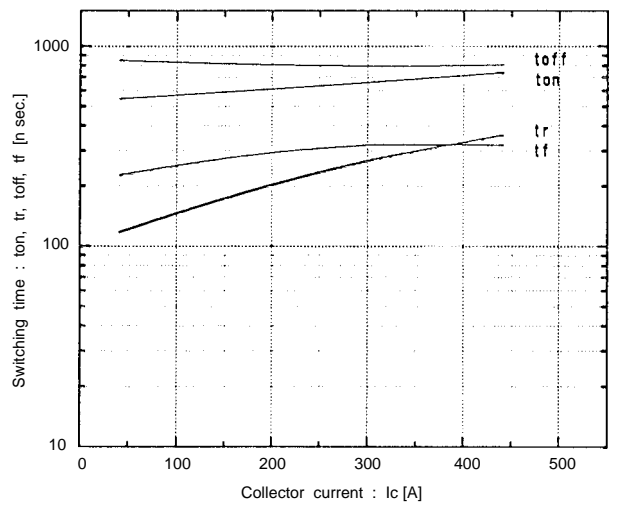
Collector-Emitter vs. Gate-Emitter voltage  
Tj=125°C



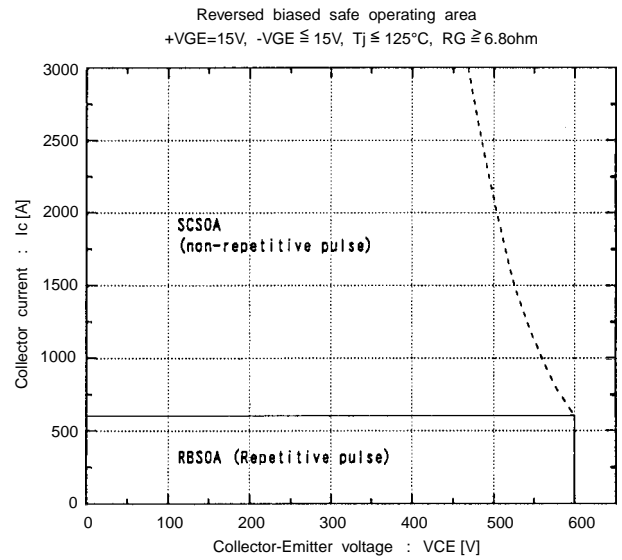
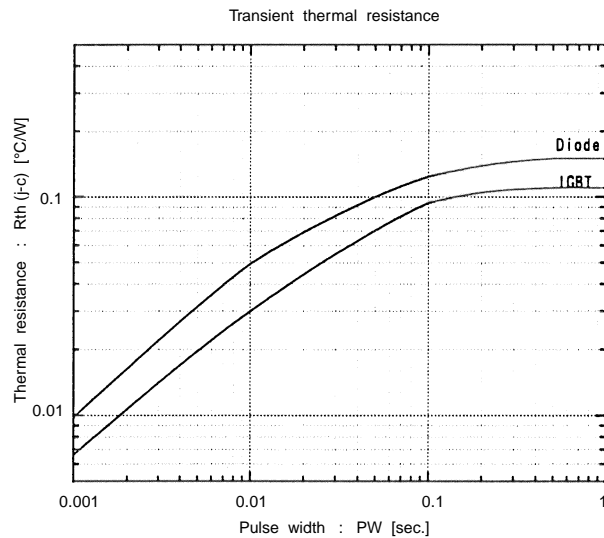
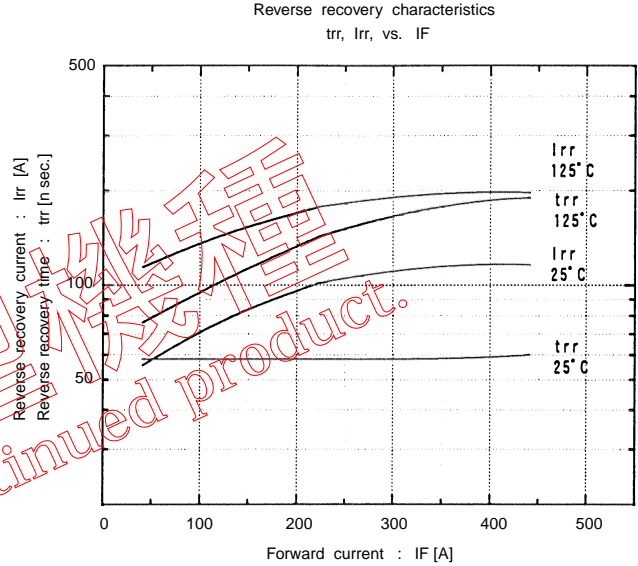
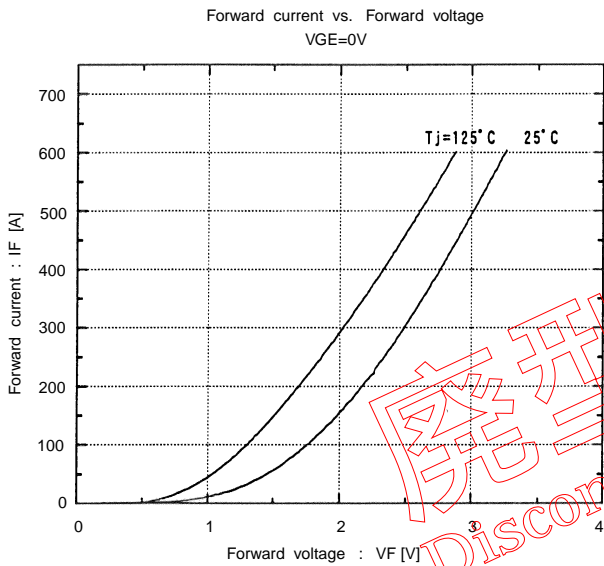
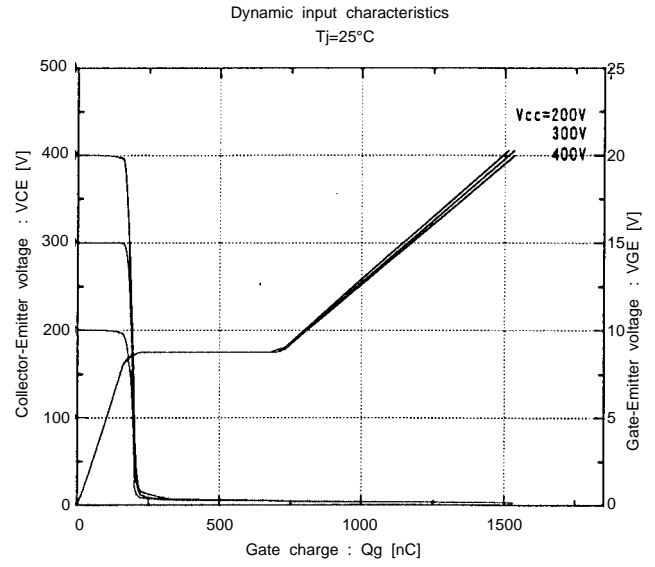
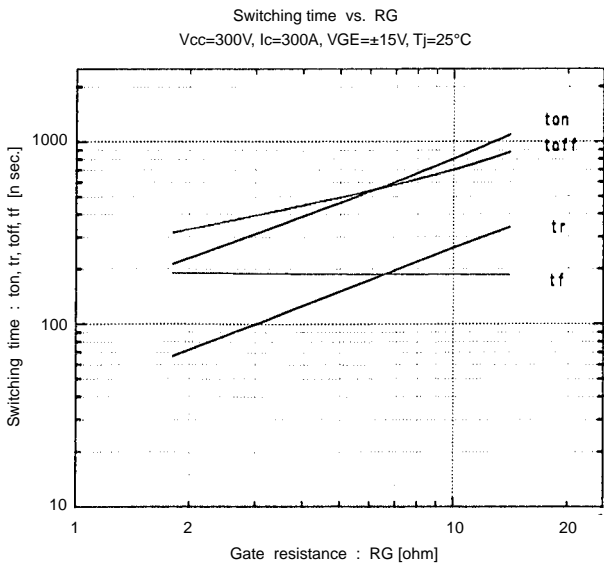
Switching time vs. Collector current  
Vcc=300V, RG=6.8 ohm, VGE=±15V, Tj=25°C



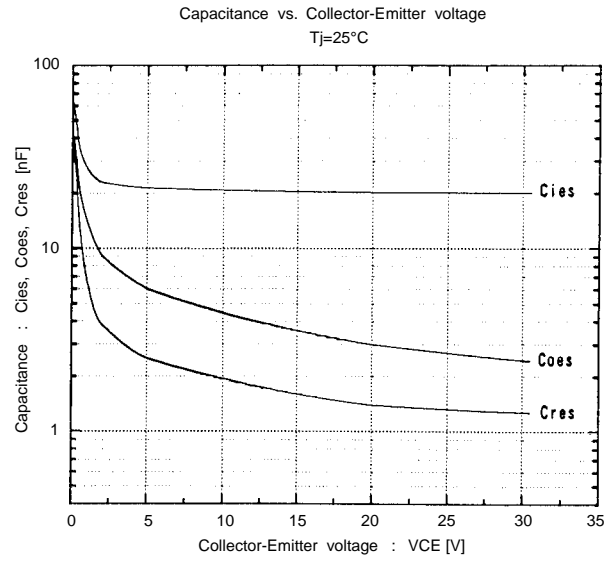
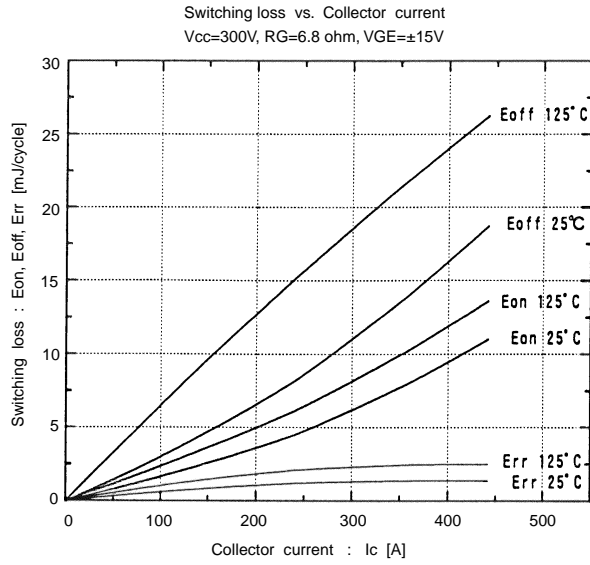
Switching time vs. Collector current  
Vcc=300V, RG=6.8 ohm, VGE=±15V, Tj=125°C



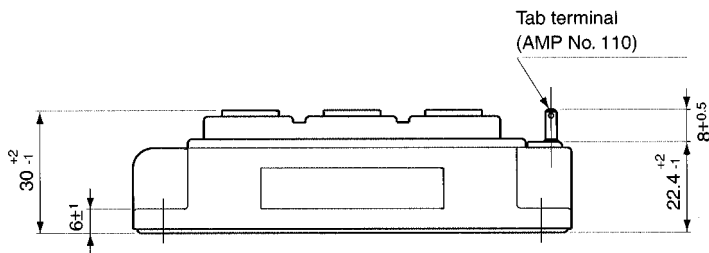
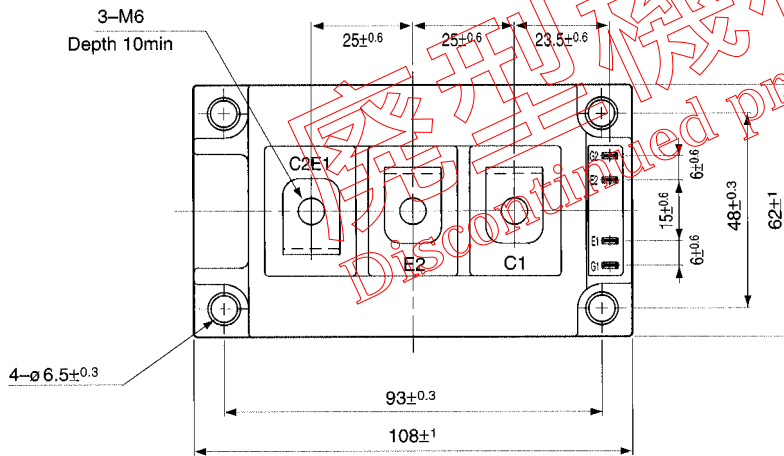
廢刊機 廢刊機  
 Discontinued product



Discontinued product.



■ Outline Drawings, mm



Mass : 370g